## NSN 5961-00-399-1173

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-399-1173 **Inclosure Material:** Metal **Overall Length:** 0.270 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **End Application:** F-16 aircraft. Ballistic missle early warning sys. (bmews). **Internal Configuration:** Field effect **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 drain to source voltage **Current Rating Per Characteristic:** 3.00 milliamperes zero-gate-voltage drain current and 9.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 200.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No